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November 2013

FQL40N50F

N-Channel QFET® FRFET® MOSFET 500 V, 40 A, 110 mΩ

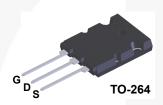
Description

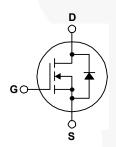
This N-Channel enhancement mode power MOSFET is • 40 A, 500 V, $R_{DS(on)}$ = 110 m Ω (Max.) @ V_{GS} = 10 V, produced using Fairchild Semiconductor's proprietary planar stripe and DMOS technology. This advanced MOSFET technology has been especially tailored to reduce on-state • Low Gate Charge (Typ. 155 nC) resistance, and to provide superior switching performance • Low Crss (Typ. 95 pF) and high avalanche energy strength. These devices are suitable for switched mode power supplies, active power • 100% Avalanche Tested factor correction (PFC), and electronic lamp ballasts.

Features

- $I_D = 20 A$

- · Fast Recovery Body Diode (Max. 250 ns)





Absolute Maximum Ratings T_C = 25°C unless otherwise noted.

Symbol	Parameter	FQL40N50F	Unit
V _{DSS}	Drain-Source Voltage	500	V
I _D	Drain Current - Continuous (T _C = 25°C)	40	Α
	- Continuous (T _C = 100°C)	25	Α
I _{DM}	Drain Current - Pulsed (No	ote 1) 160	Α
V _{GSS}	Gate-Source Voltage	± 30	V
E _{AS}	Single Pulsed Avalanche Energy (No	ote 2) 1800	mJ
I _{AR}	Avalanche Current (No	ote 1) 40	Α
E _{AR}	Repetitive Avalanche Energy (No	ote 1) 46	mJ
dv/dt	Peak Diode Recovery dv/dt (No	ote 3) 20	V/ns
P_{D}	Power Dissipation (T _C = 25°C)	460	W
	- Derate above 25°C	3.7	W/°C
T _J , T _{STG}	Operating and Storage Temperature Range	-55 to +150	°C
T _L	Maximum lead temperature for soldering, 1/8" from case for 5 seconds.	300	°C

Thermal Characteristics

Symbol	Parameter	FQL40N50F	Unit	
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case, Max.	0.27	°C/W	
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient, Max.	30	°C/W	

Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FQL40N50F	FQL40N50F	TO-264	Tube	N/A	N/A	25 units

Symbol	Parameter	Test Conditions		Тур.	Max.	Unit
Off Cha	racteristics					
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	500			V
ΔBV _{DSS} / ΔT _J	Breakdown Voltage Temperature Coefficient	I _D = 250 μA, Referenced to 25°C		0.48		V/°(
I _{DSS}	Zana Oata Waltana Basia Oussant	V _{DS} = 500 V, V _{GS} = 0 V			50	μА
	Zero Gate Voltage Drain Current	V _{DS} = 400 V, T _C = 125°C			500	μΑ
I _{GSSF}	Gate-Body Leakage Current, Forward	V _{GS} = 30 V, V _{DS} = 0 V			100	nA
I _{GSSR}	Gate-Body Leakage Current, Reverse	V _{GS} = -30 V, V _{DS} = 0 V			-100	nA
	to-detice	1			I	
	racteristics	V = V 1 = 250 ·· A	2.0		50	1/
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu\text{A}$	3.0		5.0	V
R _{DS(on)}	Static Drain-Source On-Resistance	$V_{GS} = 10 \text{ V}, I_D = 20 \text{ A}$		0.085	0.11	Ω
9 _{FS}	Forward Transconductance	V _{DS} = 50 V, I _D = 20 A		29		S
Dynam	ic Characteristics					
C _{iss}	Input Capacitance	V _{DS} = 25 V, V _{GS} = 0 V,		5800	7500	pF
Coss	Output Capacitance	f = 1.0 MHz		880	1150	pF
C _{rss}	Reverse Transfer Capacitance			95	120	pF
Switchi	ng Characteristics					
t _{d(on)}	Turn-On Delay Time	V _{DD} = 250 V, I _D = 40 A,		140	290	ns
t _r	Turn-On Rise Time	$R_{G} = 25 \Omega$		440	890	ns
t _{d(off)}	Turn-Off Delay Time	1.6 20 22		350	700	ns
t _f	Turn-Off Fall Time	(Note 4)		250	500	ns
Qg	Total Gate Charge	V _{DS} = 400 V, I _D = 40 A,		155	200	nC
Q _{gs}	Gate-Source Charge	V _{GS} = 10 V		37		nC
Q _{gd}	Gate-Drain Charge	(Note 4)		78		nC
Drain-S	ource Diode Characteristics a	nd Maximum Ratings				
I _S	Maximum Continuous Drain-Source Diode Forward Current				40	Α
I _{SM}	Maximum Pulsed Drain-Source Diode Forward Current				160	Α
V_{SD}	Drain-Source Diode Forward Voltage	V _{GS} = 0 V, I _S = 40 A			1.4	V
t _{rr}	Reverse Recovery Time	$V_{GS} = 0 \text{ V}, I_S = 40 \text{ A},$			250	ns
Q _{rr}	Reverse Recovery Charge	dI _F / dt = 100 A/μs		1.3	///	μC

- 1. Repetitive rating : pulse-width limited by maximum junction temperature.
- 2. L = 2.0 mH, I_{AS} = 40 A, V_{DD} = 50 V, R_G = 25 Ω , starting T_J = 25°C. 3. I_{SD} \leq 40 A, di/dt \leq 200 A/ μ s , V_{DD} \leq BV_{DSS}, starting T_J = 25°C. 4. Essentially independent of operating temperature.

Typical Characteristics

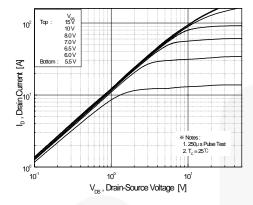


Figure 1. On-Region Characteristics

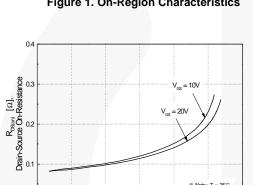


Figure 3. On-Resistance Variation vs **Drain Current and Gate Voltage**

90

In, Drain Current [A]

30

60

150

180

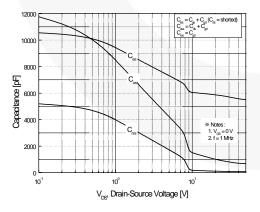


Figure 5. Capacitance Characteristics

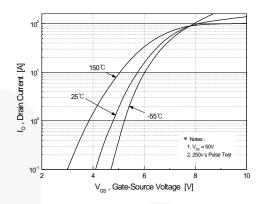


Figure 2. Transfer Characteristics

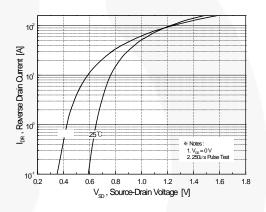


Figure 4. Body Diode Forward Voltage **Variation with Source Current** and Temperature

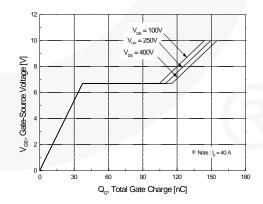


Figure 6. Gate Charge Characteristics

(Dezignation) 1.0 (Dezignation)

Typical Characteristics (Continued)

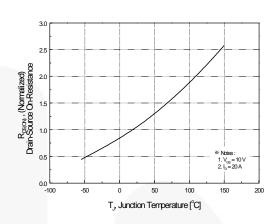
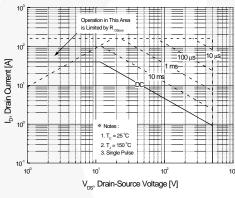


Figure 8. On-Resistance Variation vs Temperature



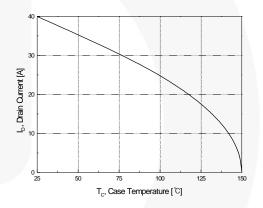


Figure 9. Maximum Safe Operating Area

Figure 10. Maximum Drain Current vs Case Temperature

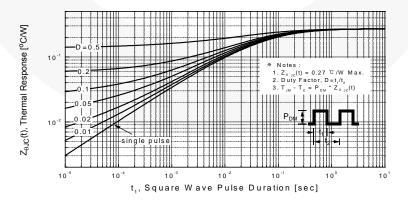


Figure 11. Transient Thermal Response Curve

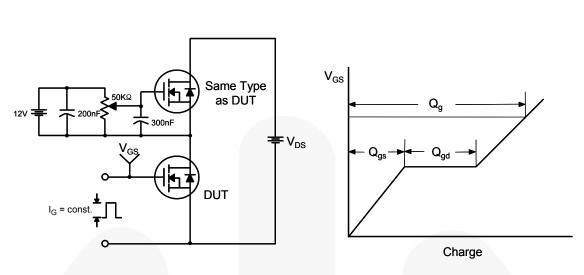


Figure 12. Gate Charge Test Circuit & Waveform

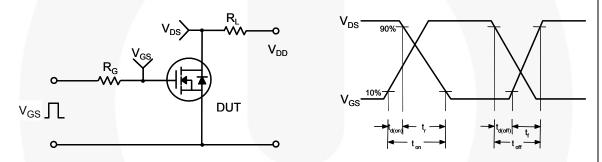


Figure 13. Resistive Switching Test Circuit & Waveforms

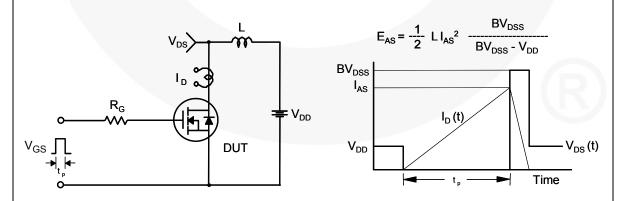
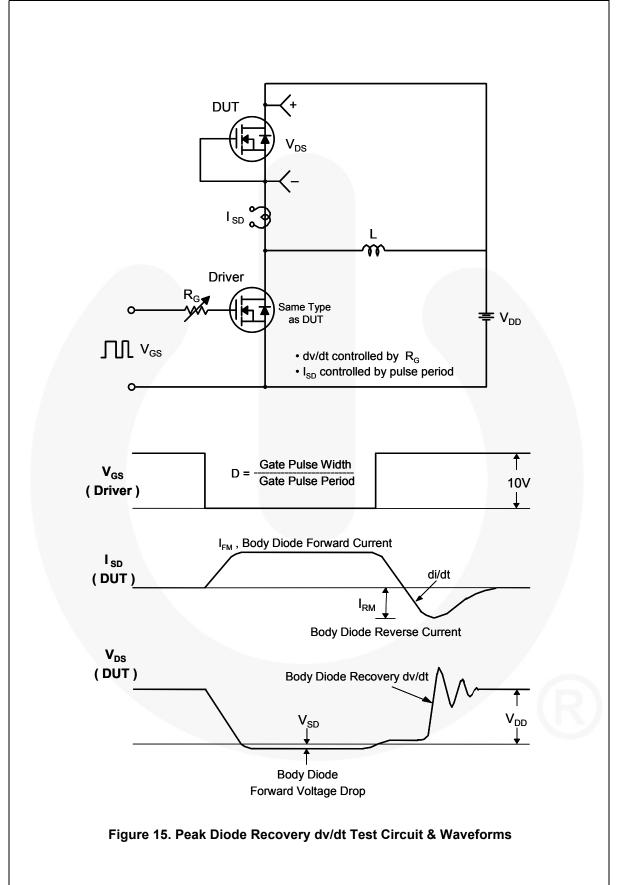
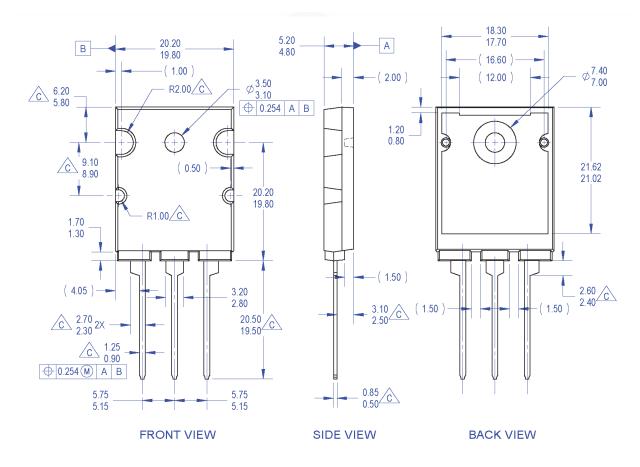
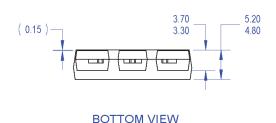


Figure 14. Unclamped Inductive Switching Test Circuit & Waveforms



Mechanical Dimensions





NOTES:

- A. PACKAGE REFERENCE: JEDEC TO264 VARIATION AA
- B. ALL DIMENSIONS ARE IN MILLIMETERS.
- OUT OF JEDEC STANDARD VALUE.
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- G. DRAWING FILE NAME: TO264A03REV1

Figure 16. TO264, Molded, 3-Lead, Jedec Variation AA

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